

Effect of calcium addition on microstructure and electrical properties of lead zirconate titanate ceramic compositions near MPB

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Calcium modified lead zirconate titanate ceramic compositions Pb_(1-x)Ca_xZr_{0.52}Ti_{0.48}O₃, where x=0, 0.02, 0.04, 0.06, 0.08, 0.1, have been prepared by solid state reaction method using wet milling. Scanning Electron Microscopy (SEM) studies have been carried out to see the variation in the grain size with calcium addition. A correlation of the dielectric constant and dielectric loss with grain size effect is presented in this paper. A monotonic decrease in the transition temperature along with more diffuseness in paraelectric-ferroelectric phase transition is observed with increasing calcium content. The values of activation energy (E_a) for the samples, calculated for ferroelectric region near phase transition temperature, are found to be in the range of approximately 0.6-1.0 eV which reflects that the main charge carriers responsible for conduction at higher temperatures are oxygen ion vacancies.

Keywords: PZT, Perovskite, SEM, Solid state reaction.

Introduction

Lead zirconate titanate (PZT) with general formula PbZr_xTi_{1-x}O₃ is a promising ceramic material for vast number of commercial applications viz. transducers, actuators, FeRAMs, sensors etc. in its bulk as well as thin and thick film forms because of its excellent dielectric, piezoelectric and ferroelectric properties [1-4]. It belongs to the family of perovskites with ABO₃ structure. Being a solid solution of lead zirconate (PbZrO₃) and lead titanate (PbTiO₃), different Zr/Ti ratios result into different compositions of PZT having different structural and electrical properties. It is reported [5] to have ferroelectric phases: tetragonal phase in Tirich side and rhombohedral phase in Zr-rich side of the binary system. The boundary between these two phases is called morphotropic phase boundary (MPB). PZT compositions specifically near MPB have always kept researchers motivated (Zr/Ti=52/48) to perform more studies due to their extraordinary dielectric and electromechanical properties [5-7].

Besides altering Zr/Ti ratio, the properties of PZT ceramics can also be tailored by using various modifiers. Modified PZT composition are widely being studied and used for specific applications. Acceptor, donor and isovalent additives have been in use as modifiers which can replace the atoms at A- or B-sites of ABO₃ structure resulting in new compositions [8, 9]. The materials called hard PZT materials can be obtained by using acceptor additives such as Na⁺ or K⁺ which replace Pb⁺², or Fe⁺³ that substitutes for Zr⁺⁴. Donor additives with the cations such as Nd⁺³ or La⁺³ substituting for Pb⁺², or Nb⁺⁵ replacing Zr⁺⁴ in PZT perovskite structure produce compositions called soft PZT materials. Isovalent additives with substituting ions e.g., Ba⁺², Ca⁺², Mg⁺² or Sr^{+2} having same valency as that of Pb^{+2} or Sn^{+4} which is isovalent to Zr⁺⁴ are being used for producing materials with specific properties. Modification using Ca⁺² or Sr⁺² has been reported to enhance dielectric and electromechanical response in PZT-based ceramics [8-12].

According to various research papers available on the effect of calcium addition in lead titanate ceramics, the addition of calcium has shown improved electrical properties of the resulting material [13-15]. In view of comparatively lesser number similar reports on calcium modified PZT compositions specifically near MPB, we have carried out the present work. We are studying the effect of calcium addition on microstructure and electrical properties of PZT ceramic compositions with Zr/ Ti=52/48 prepared via solid state reaction method using wet milling. Scanning Electron Microscopy (SEM), dielectric and ac conductivity studies have been performed on the prepared samples. A correlation of dielectric properties of the samples with their microstructure and grain size effect is observed and presented.

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Experimental

Synthesis by solid state reaction method

Synthesis of Pb_(1-x)Ca_xZr_{0.52}Ti_{0.48}O₃ ceramic compositions (where x=0, 0.02, 0.04, 0.06, 0.08, 0.1) with titular representation as APC0 (unmodified or pure PZT composition), APC2, APC4, APC6, APC8 and APC10 respectively was done by solid state reaction method using wet milling, the detailed process has been communicated elsewhere. Briefly, high purity lead (II) oxide (PbO) with 5 mol% extra PbO, zirconium (IV) oxide (ZrO₂), titanium (IV) oxide (TiO₂) and calcium carbonate (CaCO₃) were weighed accurately as per stoichiometry requirements for the respective compositions and were mixed thoroughly. The mixture was ball milled in a high energy ball mill for 5 h using isopropanol as a wet milling agent. Oven dried ball milled powders were calcined at 850 °C and 900 °C in continuation for two hours each. Calcined powders of each composition were mixed with polyvinyl alcohol (PVA) binder and were uniaxially cold pressed into pellets by applying pressure of ~40 MPa. Sintering of pellets was done for two hours at 1250 °C in enclosed alumina crucibles.

Characterization

Density of the samples has been measured using Archemedes principle at room temperature taking water as the medium. Density values of all the samples are found to be more than 95% of the reported density (~7.95 g/cm³) of pure PZT [16]. X-ray powder diffractometer (Philips, PW 1830 generator) with CuK α radiation ($\lambda = 1.5405$ Å) in the range of Bragg angles 2 θ (20° $\leq 2\theta \leq 70^{\circ}$) was used to carry out phase formation in calcined powders.

The surface morphology of sintered and gold coated samples was studied at room temperature using scanning electron microscopy (SEM) (ZEISS Model-MA 15).

For electrical characterization, both sides of the sintered pellets were gold sputtered using Desk II TSC Cold Sputter/ Etch Unit for making the electrodes. Precision Impedence Analyzer (Wayne Kerr-6500B Series) was used to study the frequency and temperature dependence of dielectric constant (at different frequencies ranging from 100 Hz to 1 MHz).

Results and Discussion

X-Ray diffraction studies

The XRD patterns of calcined powders of pure and calcium modified compositions as shown in Fig. 1, are found to be sharp with distinct single diffraction peaks which indicates homogeneity and good crystallization of the calcined powders. These samples have perovskite phase without any secondary or pyrochlore phase. This shows the complete diffusion of calcium into PZT lattice for each studied composition.



Fig. 1. XRD patterns of pure and calcium modified PZT ($Pb_{(1-x_3)}Ca_xZr_{0.52}Ti_{0.48}O_3$) calcined powders (calcined at 850 °C and 900 °C in continuation for two hours each).

SEM analysis

The SEM micrographs of pure and calcium modified PZT are shown in Fig. 2. A comparative study has been carried out by keeping the magnification the same. Most of the grains are in honeycomb shape and are compactly arranged through the entire surface of the samples. The size of the grains is measured using 'ImageJ' software.

The effect of calcium content on microstructure of PZT ceramics is summarized as follows:

- Grain size decreases from $10-15 \ \mu m$ for unmodified sample (APC0) to 5-11 $\ \mu m$ for 10 mol% calcium modified (APC10) sample. Table 1 lists the size range of the grains for all the samples of APC series. The reason for the overall decreasing trend of grain size with increasing calcium content can be attributed to segregation of calcium at the grain boundaries [12].
- Variation in the grain size increases with increasing calcium content.
- The porosity is seen to increase with increasing calcium content up to 6 mol% while the microstructure seems to be denser for the samples with 8 mol% and 10 mol% calcium concentrations.
- Diffusion of grains is seen for the samples APC6, APC8 and APC10.





Table 1. Size range of Grains for samples of APC series

Sample Code	APC0	APC2	APC4	APC6	APC8	APC10
Grain size (µm)	10-15	10-15	6-13	8-13	6-12	5-11

Electrical Characterization

Dielectric properties

The effect of calcium substitution on dielectric properties of the samples along with the possible

explanations is summarized as follows:

• The variation of dielectric constant (ε') and dielectric loss tangent or dissipation factor (tan δ) at room temperature with frequency for pure and calcium

modified PZT ceramics are shown in Figs. 3 (a) and (b).

It may be noted that in all the samples there is a decrease in the dielectric constant with increasing frequency. This frequency dispersion behavior of dielectric constant is characteristic of ferroelectric materials [17].

• The values of ε' and $\tan \delta$ corresponding to frequency 10 kHz for the samples at room temperature are given in Table 2. The value of ε' decreases with increasing calcium content up to 6 mol % and then increases for the samples with 8 and 10 mol% calcium concentrations as also depicted in the inset of Fig. 3(a).

This may broadly be explained by scanning electron micrographs (Fig. 2) which show that with increasing calcium content up to 6 mol%, porosity increases while with further increase of calcium content the samples exhibit denser microstructure.

Also, in bulk ferroelectric ceramics, the room temperature dielectric response is reported to be due to an interplay of intrinsic (i.e., lattice linked response) and extrinsic contributions (which originate from domain wall motion, phase boundary and space charge etc.) [17, 18]. In PZT based ceramics both intrinsic and extrinsic contributions are influenced by the grain size variations [17-21]. In small grains, the intrinsic effects become more pronounced because of internal stresses and the depolarizing field, while the extrinsic effects get reduced due to decrease in domain wall density. In large grains, extrinsic contributions become more significant than intrinsic contributions because in larger grains the internal stresses and depolarizing fields are compensated by the formation of domain wall structures [21]. As the domain formation is suppressed in small grain size ceramics, the remaining stress increases with decreasing grain size and hence leads to the deformation of the crystal structure [21, 22].

So, the addition of calcium clearly has following impacts:

- Reduction of grain size
- Shifting of phase boundary by changing the unit cell structure
- Increase in defect density

For unmodified sample, most of the grains are large in size as shown in Fig. 2. Therefore, they contain large number of domains and hence large number of domain walls. Large number of domains are responsible for large dielectric constant while dielectric loss is because of the motion of domain walls. For the observed trend in the values of ε' for our samples at room temperature, we suggest that the extrinsic contributions are more pronounced in the samples with calcium content up to 6 mol%. With further decrease in the grain size, i.e., in case of APC8 and APC10 samples, the effect of internal stress becomes more marked over domain wall motion which causes an increase in the value of the room temperature dielectric constant. As far as the observed trend in the values of $tan \delta$ at room temperature for our samples is concerned, it can be explained on the basis of two factors viz. reduced domain wall density and increased defect density as a result of increasing calcium



Fig. 3. (a) Frequency dependence of ε' at room temperature for the ceramics of APC Series (Inset Fig. 3(a): Variation of ε' with calcium concentration at various frequencies) (b) Frequency dependence of $\tan \delta$ at room temperature for the samples of APC Series.

Table 2. Values of ε' and tan δ at 10 kHz for the samples of APC series at room temperature

Sample Code	APC0	APC2	APC4	APC6	APC8	APC10
$\varepsilon'(\text{RT})$ (10 kHz)	924	885	849	814	864	880
$\tan\delta(\text{RT})$ (10 kHz)	1.0×10^{-2}	0.94×10^{-2}	0.88×10^{-2}	0.98×10^{-2}	0.87×10^{-2}	1.8×10^{-2}

RT- Room Temperature

content. As the calcium concentration is increasing in the samples, although domain wall density reduces while the interaction between the defects and domain walls which constrains the domain wall motion, i.e., 'pinning' increases. This results in the reduction of $\tan \delta$ for the samples up to 4 mol% calcium concentrations. Beyond this composition, i.e., for APC6. APC8 and APC10 compositions, there is significant reduction in domain wall density such that not many domain wall structures are available for interaction with defects, i.e., pinning gets reduced drastically in these compositions thereby increasing the dielectric loss in the samples.

Fig. 4 shows the variation of ε' and $\tan \delta$ with temperature at different frequencies for all the compositions. The dielectric constant maxima corresponding to ferroelectric-paraelectric phase transition gets broadened with increasing calcium. This indicates that the ferroelectricparaelectric phase transition for calcium modified ceramics is of diffuse-type. The observed broadening or diffuseness in dielectric constant vs. temperature plot can be ascribed to the distribution of transition temperature for individual grains [23-26].

The degree of diffuseness in the observed variation of dielectric constant called diffusivity (γ) can be estimated using modified Curie-Weiss relation [27, 28]:

$$\frac{1}{\varepsilon'} = \frac{1}{\varepsilon'_{max}} = \frac{(T - T_{max})\gamma}{C_1}$$
(1)

where C_1 and T_{max} are the Curie-Weiss-like constant and the temperature corresponding to the dielectric maximum respectively. The mean value of γ is assessed from $\ln(1/\varepsilon' - 1/\varepsilon'_{max})$ versus $\ln(T - T_{max})$ plot (depicted in Fig. 5 for frequency 10 kHz).

Although for diffuse phase transitions, no sharp



Fig. 4. Temperature dependence of ε' and tan δ at various frequencies for the ceramic compositions of APC series.

transition temperature is observed, but for convenience, the term T_C will be used in place of T_{max} for further discussion. The limiting value of γ is (a) 1 for normal ferroelectrics which reduces the equation (1) to Curie-Weiss law and (b) 2 for an ideal relaxor ferroelectric [27]. Also, its value is reported to increase with decreasing grain size and increasing frequency [29]. The value of γ for all prepared compositions, calculated at various frequencies and listed in Table 3, shows an increasing trend with increasing calcium content.

A careful examination of the data also shows that T_C is insensitive to the change in frequency for the samples APC0 (unmodified) and APC2 which indicates that these samples have no relaxor properties. The samples APC4, APC6, APC8 and APC10 however, show sensitivity of T_C with frequency i.e., T_C tends to shift right to slightly higher value with increasing frequency. So, the compositions APC4, APC6, APC8 and APC10 show weak relaxor behavior. We can therefore, infer that there is a transition from normal ferroelectric (FE) to relaxor ferroelectric (RFE) behavior from APC2 to APC4. Also, we observe that APC6 sample exhibits the strongest relaxor behavior in the studied composition and frequency range. This can also be confirmed by the diffusivity values given in Table 3. The diffusivity at a given frequency increases with calcium content up to 6



Fig. 5. Linear fit plots of modified Curie-Weiss Law for pure and calcium modified PZT ceramics.

Table 3. Values of γ for pure and calcium modified PZT ceramics at various frequencies

Sample Code	γ					
	1 kHz	10 kHz	100 kHz	1 MHz		
APC0	1.19	1.41	1.49	1.52		
APC2	1.23	1.56	1.75	1.83		
APC4	1.41	1.72	1.81	1.89		
APC6	1.74	1.93	2.04	2.22		
APC8	1.56	1.69	1.77	1.72		
APC10	1.92	2.12	2.15	2.04		

mol%, then decreases for APC8 and again increases for APC10. The possible explanation for this in our samples is that there is onset of relaxor behavior at 4 mol% calcium content which becomes stronger for APC6 and goes weaker for APC8 and APC10 compositions. The higher value of γ for APC10 composition may be because of the large variation in the grain sizes. The detailed study is, however, required to confirm this on PZT compositions with intermediate as well as higher calcium contents.

Equations (2) and (3) respectively relate the diffuseness of phase transition to the temperature width ΔT and the degree of relaxation behavior to ΔT_{relax} [30, 31]:

$$\Delta T = T_{0.9\varepsilon'(\text{max})} - T_{max} \qquad \text{(for } T_{0.9\varepsilon'(\text{max})} > T_{max}\text{)} \qquad (2)$$

$$\Delta T_{relax} = T_{max} (1 \text{ MHz}) - T_{max} (100 \text{ Hz})$$
(3)

where ε'_{max} and $T_{0.9\varepsilon'(max)}$ are the maximum ε' and temperature corresponding to 90% of ε'_{max} for $T > T_{max}$, respectively. Using equations (1-3), the variation of γ , ΔT and ΔT_{relax} vs. calcium concentration has been plotted in Fig. 6.

Fig. 7(a) displays the temperature dependence of ε' at 10 kHz for all the compositions studied in the present paper.

The transition temperature (T_C) decreases monotonically with increasing calcium content and is shown in the inset of Fig. 7(a). The decline in the T_C value may also be attributed to the rising internal stress with decreasing grain size due to increasing calcium content [21].

The temperature dependence of $\tan \delta$ for all the prepared samples at 10 kHz depicted in Fig. 7(b) indicate that the values of $\tan \delta$ and its variation with temperature are small for the temperatures below T_C . Beyond T_C , its values display a significant increase which is attributed to the existence of space charge polarization in the materials [25, 26]. However, with increasing frequency, the increase in the value of $\tan \delta$



Fig. 6. Variation of ΔT , ΔT_{relax} and γ vs. calcium concentration.



Fig. 7. (a) Temperature dependence of ε' for the samples of APC series at 10 kHz (Inset Fig. 7 (a): Variation of transition temperature with calcium concentration at 10 kHz) (b) Temperature dependence of tan δ for the samples of APC series at 10 kHz.

near T_C becomes less prominent for the given materials. Table 4 provides the values of T_C and ε'_{max} at 10 kHz.

AC conductivity studies

Fig. 8 depicts the frequency dependence of ac conductivity (σ_{ac}) of ceramics of APC series at different temperatures. For a given temperature, frequency dependence behavior of ac conductivity can be explained by the Jonscher power law:

$$\sigma_{ac} = \sigma_{dc} + A\omega^n \tag{4}$$

where σ_{ac} is the dc (or very low frequency) conductivity, A is a constant for given temperature and the exponent *n* is reported to lie in the range 0 < n < 1 [32]. With increase in temperature, the increase in σ_{ac} for all the samples is noted. At higher temperatures, conductivity spectrum displays a frequency independent or plateau region at lower frequencies and dispersive region at higher frequencies. The plateau region of ac conductivity that broadens with rise in temperatures suggests that the dc conduction process is becoming more dominant with increasing temperature. This also implies that conductivity at higher temperatures is primarily activated by increasing the temperature itself [33].

The temperature dependence of ac conductivity can be explained by Arrhenius formula:

$$\sigma_{ac} = \sigma_0 e^{-E_a/kT} \tag{5}$$

where E_a and k are the activation energy and the Boltzmann constant respectively. Lower values of acti-

vation energy imply higher conductivity. For dielectric materials higher conductivity is detrimental to its dielectric properties. In case of Pb-based ferroelectrics, in the high temperature regions, the reasons for conduction process have been linked to the electro-migration of singly and doubly ionized oxygen vacancies and hopping electrons between Ti⁺⁴ and Ti⁺³ ions which are the two localized states of titanium [34,3 5]. The E_a values associated with singly ionized oxygen vacancies are reported to be in the range 0.3 eV-0.4 eV and with doubly ionized oxygen vacancies in the range 0.6 eV-1.2 eV [35, 36]. Also, low value of E_a has been attributed to high concentration of oxygen vacancies and vice versa [37].

Fig. 9 shows the curves plotted between $\ln(\sigma_{ac})$ and 1000/T for all the studied compositions.

The E_a values are calculated for all the prepared compositions from the slope of $\ln(\sigma_{ac})$ vs. 1000/Tcurves near transition temperature in the ferroelectric region for the frequency 10 kHz and are listed in Table 4. The values are observed to lie in the range 0.6 eV-1.02 eV which are consistent with the reported values associated with the movement of doubly ionized oxygen vacancies. We therefore, infer that the main cause for conductivity, for our samples in the mentioned temperature zone, is the electro-migration of doubly ionized oxygen vacancies.

The values of E_a calculated at 10 kHz for modified samples are greater than that for unmodified i.e., APC0 sample in studied temperature range. In general, this increase in E_a with increasing calcium addition has

Table 4. Values of T_{max} or T_C , ε'_{max} , E_a at 10 kHz for unmodified and calcium modified PZT ceramics

Sample Code	APC0	APC2	APC4	APC6	APC8	APC10
T_{ma} or T_C (°C)	327	312	291	282	267	243
ε' _{max}	34700	27068	25952	17545	13923	9677
$E_a (\mathrm{eV})$	0.60	0.83	0.76	0.85	0.90	1.02



Fig. 8. Frequency dependence of ac conductivity at various temperatures for the samples of APC Series.

been attributed to the reduction in grain size. The decrease in grain size impedes the short-range hopping of oxygen vacancies and hence enhances E_a [38, 39]. Regarding higher value of E_a for APC2 than that for APC4, we relate the observed trend of E_a with transition of normal FE to RFE from APC2 to APC4. It is reported in literature that the ferroelectric materials showing relaxor behavior possess higher degree of structural disorder and lattice defects which promote the formation of polar nano regions [39-42]. At higher temperatures, these defects contribute to increased conductivity and hence lower E_a [38, 40]. In APC2 sample that shows normal FE behavior, at higher temperatures.

perature, grain size effect seems to determine E_a . While in the case of samples with calcium content higher than 2 mol% which show weak relaxor behavior, the observed trend in E_a can be explained on the basis of the combined effect of (a) decreased grain size and hence decreased concentration of oxygen vacancies leading to higher E_a and (b) greater structural disorder and lattice defects which tend to increase the conductivity at higher temperature and hence decreases E_a . Also, since the samples APC4, APC6, APC8 and APC10 show weak relaxor behavior, the main charge carriers responsible for conduction at higher temperatures are oxygen ion vacancies.



Fig. 9. Temperature dependence of ac conductivity for the samples of APC series at different frequencies.

Conclusions

Increasing calcium addition in the studied $Pb_{(1-x)}$ Ca_xZr_{0.52}Ti_{0.48}O₃ ceramic compositions results in the reduction of grain size. An interplay of intrinsic and extrinsic contributions which are influenced by grain size variations is responsible for the observed trend in the values of dielectric constant at room temperature. With increasing calcium concentration, the ferroelectricparaelectric phase transition becomes more diffused for the samples and a monotonic decrease in T_C is noted which is attributed to increasing internal stress. Weak relaxor properties are observed in the samples with calcium content more than 2 mol% in the studied composition and frequency range. From the ac conductivity studies, the value of activation energy, calculated for the ferroelectric region near phase transition temperature at the frequency 10 kHz, is greater for calcium modified samples than that for unmodified sample. This is due to decrease in grain size that results into decreased concentration of oxygen ion vacancies. For the samples with calcium content higher than 2 mol%, in addition to grain size effect, higher degree of disorder and lattice defects are also responsible for determining the value of E_q .

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Conflict of Interest

The authors declare no conflict of interest.

References

- 1. G.H. Haertling, J. Am. Ceram. Soc. 82[4] (1999) 797-818.
- 2. K. Kim, and S. Lee, J. Appl. Phys. 100[5] (2006) 51604(1-11).
- 3. A. Presas, Y. Luo, Z. Wang, D. Valentin, and M. Egusquiza, Sensors. 18[7] (2018) 2251(1-21).
- 4. B. Tiwari, T. Babu, and R.N.P. Choudhary, in Materials Today: Proceedings of the 1st International Conference on Energy, Material Sciences and Mechanical Engineering, Oct 31-Nov 1, 2020, edited by H. Kumar, P. Jain, and V. Pandey (Elsevier Ltd., 2021) p. 407.
- 5. B. Jaffe, W.R. Cook, and H. Jaffe, in "Piezoelectric Ceramics" (Academic Press, 1971).
- Y. Xu, in "Ferroelectric Materials and Their Applications" (Elsevier Science, 2013).
- A.S. Bhalla, R. Guo, and E.F. Alberta, Mater. Lett. 54[4] (2002) 264-268.
- R.C. Buchanan, in "Ceramic Materials for Electronics" (Boca Raton: CRC, 2018).
- B. Cherdhirunkorn, B. Pidthong, P. Jeamwutthisak, D.A. Hall, M. Shuaib, and T. Tunkasiri, J. Ceram. Process. Res. 13[2] (2012) s323-s327.A. Sachdeva, V. Luthra, P. Gautam, and R.P. Tandon, Integr. Ferroelectr. 122[1] (2010) 74-82.
- M.S. Silva, A.A. Cavalheiro, M.A. Zaghete, M. Cilense, E. Longo, G.F. Cavenago, R.G. Dias, L.L. Silva, and F.V. Motta, Mater. Sci. Forum. 805 (2015) 298-304.
- S. Sen, R.N.P. Choudhary, and P. Pramanik, Physica B. 387 (2007) 56–62.
- 12. D. Damjanovic, T.R. Gururaja, and L.E. Cross, Am. Ceram. Soc. Bull. 66[4] (1987) 699–703.
- A. Seifert, L. Sagalowicz, P. Muralt, and N. Setter, J. Mater. Res. 14[5] (1999) 2012-2022.
- A.L. Kholkin, M.L. Calzada, P. Ramos, J. Mendiola, and N. Setter, Appl. Phys. Lett. 69[23] (1996) 3602–3604.
- P. Duran and C. Moure, J. Mater. Sci. 20[3] (1985) 827-833.
- K.C. Kao, in "Dielectric Phenomena in Solids" (Elsevier Academic Press, 2004).

- R. Waser, U. Böttger, and S. Tiedke "Polar Oxides: Properties, Characterization and Imaging" (WILEY-VCH Verlag GmbH & Co. KGaA, Weinheim, 2005).
- B. Tareev, in "Physics of Dielectric Materials" (Mir Publications, 1975).
- W.A. Scchulze, and K. Ogino, Ferroelectrics. 87[1] (1988) 361-377.
- 20. T.M. Kamel, and G de With, J. Euro. Ceram. Soc. 28[4] (2008) 851-861.
- 21. S.K. Mishra, and D. Pandey, J. Phys : Condens. Matter. 7[48] (1995) 9287-9303.
- 22. R. Tickoo, R.P. Tandon, K.K. Bamzai, and P.N. Kotru, Mater. Sci. Engg. B. 103[2] (2003) 145-151.
- 23. S.R. Shannigrahi, F.E.H. Tay, K. Yao, and R.N.P. Choudhary, J. Euro. Ceram. Soc; 24[1] (2004) 163-170.
- 24. R. Ranjan, R. Kumar, B. Behera, and R.N.P. Choudhary, Mater. Chem. Phys. 115[1] (2009) 473-477.
- M.E. Lines, and A.M. Glass, in "Principles and Applications of Ferroelectrics and Related Materials" (Oxford, Clarendon, 1979).
- 26. K. Uchino, and S. Nomura, Ferroelectrics. 44[1] (1982) 55-61.
- 27. S.M. Pilgrim, A.E. Sutherland, and S.R. Winzer, J. Am. Ceram. Soc. 73[10] (1990) 3122-3125.
- 28. B.M. Jin, J. Kim, and S.C. Kim, Appl. Phys. A. 65[1] (1997) 53-56.
- 29. H.P. Soon, and J. Wang, J. Appl. Phys. 100[12] (2006) 124101(1-7).
- C.C. Tsai, S.Y. Chu, J.S. Jiang, C.S. Hong, and Y.F. Chiu, Ceram. Int. 40[8] (2014) 11713- 11725.
- A.K. Jonscher, in "Dielectric Relaxation in Solids" (Chelsea Dielectric Press, 1983).
- 32. I.W. Kim, C.W. Ahn, J.S. Kima, T.K. Song, J.S. Bae, B.C. Choi, J.H. Jeong, and J.S. Lee, Appl. Phys. Lett. 80[21] (2002) 4006-4008.
- D. Fasquelle, and J.C. Carru, J. Euro. Ceram. Soc. 28[10] (2008) 2071-2074.
- 34. A. Peláiz-Barranco, J.D.S. Guerra, R. López-Noda, and E.B. Araújo, J. Phys. D: Appl. Phys. 41[21] (2008) 215503 (1-5).
- 35. C. Ang, Z. Yu, and L.E. Cross, Phys. Rev. B. 62[1] (2000) 228-236.
- 36. G. Deng, G. Li, A. Ding, and Q. Yin, Appl. Phys. Lett. 87[19] (2005) 192905(1-3).
- 37. M. Zhou, R. Liang, Z. Zhou, and X. Dong, Inorg. Chem. Front. 6 (2019) 2148-2157.
- P. Zhao, B. Tanga, F. Sia, C. Yanga, H. Lic, and S. Zhanga, J. Euro. Ceram. Soc. 40 (2020) 1938–1946.
- 39. P. Zhao, B. Tang, F. Si, C. Yang, H. Li, and S. Zhang, IEEE Trans. Dielectr. Electr. Insul. 22(6) (2015) 3668–3675.
- 40. C. Elissalde, and J. Ravez, J. Mater. Chem. 11(8) (2001) 1957-1967.
- 41. S. Anwar, P.R. Sagdeo, and N. P. Lalla, J. Phys.: Condens. Matter, 18(13) (2006) 3455-3468.